SQJ420EP

AUTOMOTIVE

RoHS

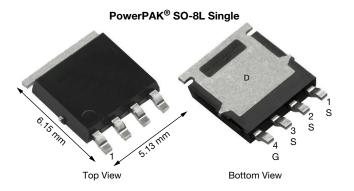
COMPLIANT HALOGEN

FREE

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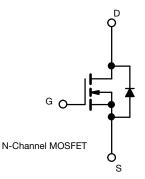
Automotive N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0100			
$R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V	0.0120			
I _D (A)	30			
Configuration	Single			
Package	PowerPAK SO-8L			

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unles	s otherwise noted	4)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	40	V	
Gate-source voltage		V _{GS}	± 20	V	
Continuous drain current	T _C = 25 °C ^a	I _D	30		
	T _C = 125 °C		26.8		
Continuous source current (diode conduction) ^a		I _S	30	А	
Pulsed drain current ^b		I _{DM}	110		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	28		
Single pulse avalanche energy	L = 0.1 MH	E _{AS}	39	mJ	
Maximum power dissipation ^b	T _C = 25 °C	P _D	45	W	
	T _C = 125 °C		15	vv	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	- °C	
Soldering recommendations (peak temperature) ^{d, e}			260	U	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^c	R _{thJA}	70	°C/W
Junction-to-case (drain)		R _{thJC}	3.3	0/10

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)

d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

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/DS aS(th) aSS DSS D(on) DS(on) DS(on) DS(on) DS(on) DS(on) DS(on)	$V_{DS} = V_{DS} = V_{DS} = V_{GS} = 0 V$ $V_{GS} = 0 V$ $V_{GS} = 0 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$ $V_{GS} = 4.5 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$	= 0, $I_D = 250 \ \mu A$ V_{GS} , $I_D = 250 \ \mu A$ 0 V, $V_{GS} = \pm 20 \ V$ $V_{DS} = 40 \ V$ $V_{DS} = 40 \ V$, $T_J = 125 \ ^{\circ}C$ $V_{DS} = 40 \ V$, $T_J = 175 \ ^{\circ}C$ $V_{DS} \ge 5 \ V$ $I_D = 9.7 \ A$ $I_D = 8 \ A$ $I_D = 9.7 \ A$, $T_J = 125 \ ^{\circ}C$ $I_D = 9.7 \ A$, $T_J = 125 \ ^{\circ}C$ $I_D = 9.7 \ A$, $T_J = 125 \ ^{\circ}C$ $I_D = 9.7 \ A$, $T_J = 125 \ ^{\circ}C$ $I_D = 9.7 \ A$, $T_J = 125 \ ^{\circ}C$	40 1.5 - - - 30 - - - - - - - - - - - - -	- 2.0 - - - 0.0082 0.0098 - - 68	- 2.5 ± 100 1 50 150 - 0.0100 0.0120 0.0166 0.0204 -	V nA μA A Ω S
23S(th) 23SS 20SS 20(on) 20S(on) 20S(on) 20S(on) 20Ss 20ss	$V_{DS} = V_{DS} = V_{DS} = V_{GS} = 0 V$ $V_{GS} = 0 V$ $V_{GS} = 0 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$ $V_{GS} = 4.5 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$	$V_{GS}, I_D = 250 \ \mu A$ 0 V, $V_{GS} = \pm 20 \ V$ $V_{DS} = 40 \ V$ $V_{DS} = 40 \ V$, $T_J = 125 \ ^{\circ}C$ $V_{DS} = 40 \ V$, $T_J = 175 \ ^{\circ}C$ $V_{DS} \ge 5 \ V$ $I_D = 9.7 \ A$ $I_D = 8 \ A$ $I_D = 9.7 \ A$, $T_J = 125 \ ^{\circ}C$ $I_D = 9.7 \ A$, $T_J = 125 \ ^{\circ}C$	1.5 - - - - 30 - - - - - -	- - - - 0.0082 0.0098 - - 68	± 100 1 50 150 - 0.0100 0.0120 0.0166 0.0204	nA μA A
DSS D(on) DS(on) Gfs Diss Doss	$V_{DS} = V_{GS} = 0 V$ $V_{GS} = 0 V$ $V_{GS} = 0 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$ $V_{GS} = 4.5 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$	$\begin{array}{c} 0 \text{ V, } V_{GS} = \pm 20 \text{ V} \\ \hline V_{DS} = 40 \text{ V} \\ V_{DS} = 40 \text{ V, } T_J = 125 \text{ °C} \\ \hline V_{DS} = 40 \text{ V, } T_J = 175 \text{ °C} \\ \hline V_{DS} \ge 5 \text{ V} \\ \hline I_D = 9.7 \text{ A} \\ \hline I_D = 8 \text{ A} \\ \hline I_D = 9.7 \text{ A, } T_J = 125 \text{ °C} \\ \hline I_D = 9.7 \text{ A, } T_J = 175 \text{ °C} \end{array}$	- - - 30 - - - - - -	- - - - 0.0082 0.0098 - - 68	± 100 1 50 150 - 0.0100 0.0120 0.0166 0.0204	nA μA A
DSS D(on) DS(on) Gfs Diss Doss	$V_{GS} = 0 V$ $V_{GS} = 0 V$ $V_{GS} = 0 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$ $V_{GS} = 4.5 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$ $V_{DS} = 10 V$	$V_{DS} = 40 V$ $V_{DS} = 40 V, T_J = 125 °C$ $V_{DS} = 40 V, T_J = 175 °C$ $V_{DS} \ge 5 V$ $I_D = 9.7 A$ $I_D = 8 A$ $I_D = 9.7 A, T_J = 125 °C$ $I_D = 9.7 A, T_J = 175 °C$	- - - - - - - - -	- - 0.0082 0.0098 - - 68	1 50 150 - 0.0100 0.0120 0.0166 0.0204	μΑ Α Ω
D(on) DS(on) Gfs Diss Doss	$\begin{tabular}{ c c c c c } \hline V_{GS} = 0 \ V \\ \hline V_{GS} = 0 \ V \\ \hline V_{GS} = 10 \ V \\ \hline V_{GS} = 10 \ V \\ \hline V_{GS} = 4.5 \ V \\ \hline V_{GS} = 10 \ V \\ \hline V_{GS} = 10 \ V \\ \hline V_{GS} = 10 \ V \\ \hline \end{array}$	$V_{DS} = 40 \text{ V}, \text{T}_{\text{J}} = 125 \text{ °C}$ $V_{DS} = 40 \text{ V}, \text{T}_{\text{J}} = 175 \text{ °C}$ $V_{DS} \ge 5 \text{ V}$ $I_{D} = 9.7 \text{ A}$ $I_{D} = 8 \text{ A}$ $I_{D} = 9.7 \text{ A}, \text{T}_{\text{J}} = 125 \text{ °C}$ $I_{D} = 9.7 \text{ A}, \text{T}_{\text{J}} = 175 \text{ °C}$	- - 30 - - - - -	- - 0.0082 0.0098 - - 68	50 150 - 0.0100 0.0120 0.0166 0.0204	Α Α Ω
D(on) DS(on) Gfs Diss Doss	$\label{eq:VGS} \begin{array}{c} V_{GS} = 0 \ V \\ V_{GS} = 10 \ V \\ V_{GS} = 10 \ V \\ V_{GS} = 4.5 \ V \\ V_{GS} = 10 \ V \\ V_{GS} = 10 \ V \\ V_{GS} = 10 \ V \\ V_{DS} = 10 \ V \\ \end{array}$	$V_{DS} = 40 \text{ V}, \text{T}_{J} = 175 ^{\circ}\text{C}$ $V_{DS} \ge 5 \text{ V}$ $I_{D} = 9.7 \text{ A}$ $I_{D} = 8 \text{ A}$ $I_{D} = 9.7 \text{ A}, \text{T}_{J} = 125 ^{\circ}\text{C}$ $I_{D} = 9.7 \text{ A}, \text{T}_{J} = 175 ^{\circ}\text{C}$	- 30 - - - - -	- - 0.0082 0.0098 - - 68	150 - 0.0100 0.0120 0.0166 0.0204	Α Ω
DS(on) Gfs Diss Doss	$\label{eq:VGS} \begin{array}{c} V_{GS} = 0 \ V \\ V_{GS} = 10 \ V \\ V_{GS} = 10 \ V \\ V_{GS} = 4.5 \ V \\ V_{GS} = 10 \ V \\ V_{GS} = 10 \ V \\ V_{GS} = 10 \ V \\ V_{DS} = 10 \ V \\ \end{array}$	$V_{DS} \ge 5 V$ $I_{D} = 9.7 A$ $I_{D} = 8 A$ $I_{D} = 9.7 A, T_{J} = 125 °C$ $I_{D} = 9.7 A, T_{J} = 175 °C$	30 - - - - -	- 0.0082 0.0098 - - 68	- 0.0100 0.0120 0.0166 0.0204	Ω
DS(on) Gfs Diss Doss	$V_{GS} = 10 V$ $V_{GS} = 4.5 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$ $V_{DS} = 10 V$	$V_{DS} \ge 5 V$ $I_{D} = 9.7 A$ $I_{D} = 8 A$ $I_{D} = 9.7 A, T_{J} = 125 °C$ $I_{D} = 9.7 A, T_{J} = 175 °C$	- - - -	0.0082 0.0098 - - 68	0.0100 0.0120 0.0166 0.0204	Ω
DS(on) Gfs Diss Doss	$V_{GS} = 10 V$ $V_{GS} = 4.5 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$ $V_{DS} = 10 V$	$I_D = 8 \text{ A}$ $I_D = 9.7 \text{ A}, T_J = 125 \text{ °C}$ $I_D = 9.7 \text{ A}, T_J = 175 \text{ °C}$		0.0098 - - 68	0.0120 0.0166 0.0204	
gfs Diss Doss	$V_{GS} = 4.5 V$ $V_{GS} = 10 V$ $V_{GS} = 10 V$ $V_{DS} = 10 V$	$I_D = 8 \text{ A}$ $I_D = 9.7 \text{ A}, T_J = 125 \text{ °C}$ $I_D = 9.7 \text{ A}, T_J = 175 \text{ °C}$	-	- - 68	0.0166 0.0204	
gfs Diss Doss	V _{GS} = 10 V V _{GS} = 10 V V _{DS} :	I _D = 9.7 A, T _J = 125 °C I _D = 9.7 A, T _J = 175 °C	-	- 68	0.0204	
Piss Poss	V _{GS} = 10 V V _{DS} :	I _D = 9.7 A, T _J = 175 °C	-	68		S
Piss Poss	V _{DS} :		I		-	S
Piss Poss			-	1407		
Poss	V _{GS} = 0 V		-	4 4 0 7		
Poss	V _{GS} = 0 V			1427	1860	
	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	_	193	260	pF
Srss			-	71	95	
Qq	V _{GS} = 10 V	V _{DS} = 20 V, I _D = 11.3 A	-	27	41	nC
λ ^{gs}			-	4.6	-	
2 _{ad}	1		-	4.6	-	
R _g		f = 1 MHz	0.65	1.36	2.10	Ω
d(on)			-	10	15	
t _r	- 	$V_{DD} = 20 \text{ V}, \text{ R}_1 = 13.3 \Omega$		4	10	- ns
	$V_{DD} = 20$ V, $H_{L} = 10.3 \Omega^{2}$ $I_{D} \cong 1.5$ A, $V_{GEN} = 10$ V, $R_{g} = 1 \Omega$		_	25	40	
			_	5	10	
·						I
			-	-	110	А
	$I_{\rm F} = 7 \text{A}, V_{\rm CS} = 0$		_	0.79	1.2	V
		ir - 77, VGS - 0		28	60	ns
	I _F = 5 A, di/dt = 100 A/μs		-	25	50	nC
			-	18	-	
			-	10	-	ns
	d(off) tf cs b lsM /sD trr Qrr ta tb	$\begin{array}{c c} \hline cs & b \\ \hline cs & b \\ \hline \\ \hline \\ \hline \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\$	$l_{SM} = \frac{l_{F}}{l_{F}}$ $l_{SM} = \frac{l_{F}}{l_{F}} = 7 \text{ A, } V_{GS} = 0$ $l_{Frr} = \frac{l_{F}}{l_{F}} = 5 \text{ A, } di/dt = 100 \text{ A/}\mu\text{s}$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

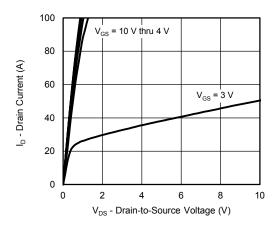
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

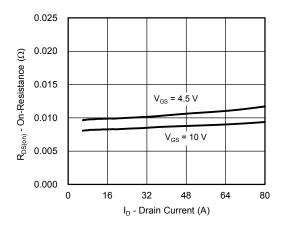
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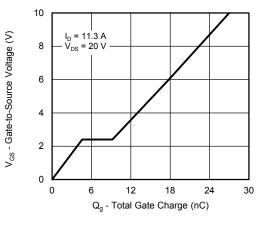
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



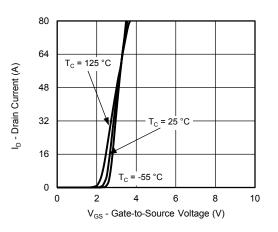
Output Characteristics



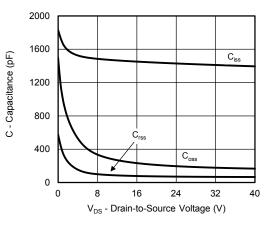
On-Resistance vs. Drain Current



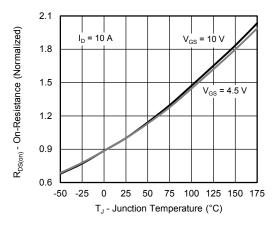
Gate Charge



Transfer Characteristics



Capacitance



On-Resistance vs. Junction Temperature

S17-0949-Rev. A, 19-Jun-17

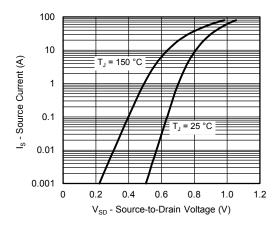
3

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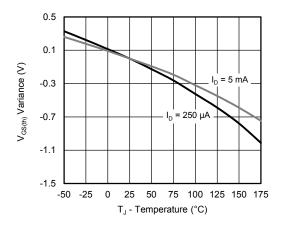
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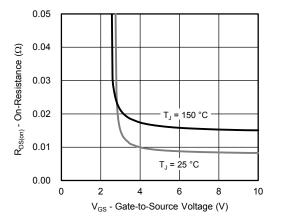
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



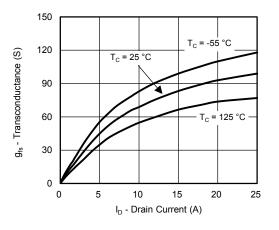
Source Drain Diode Forward Voltage



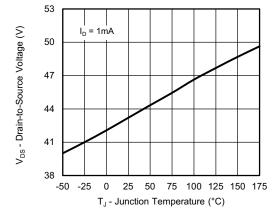




On-Resistance vs. Gate-to Source Voltage



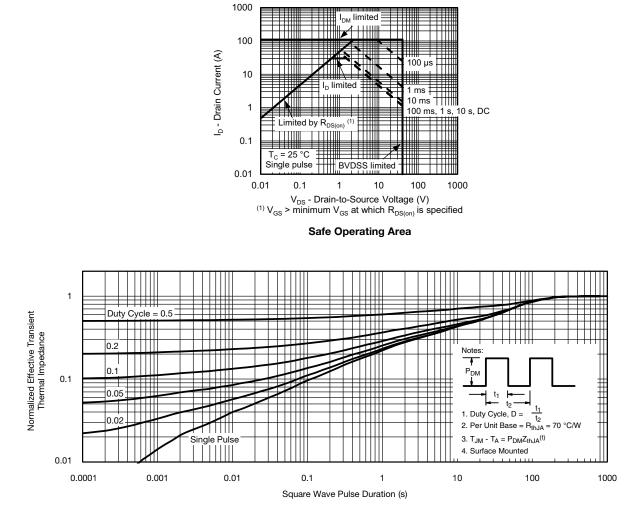




Drain Source Breakdown vs. Junction Temperature



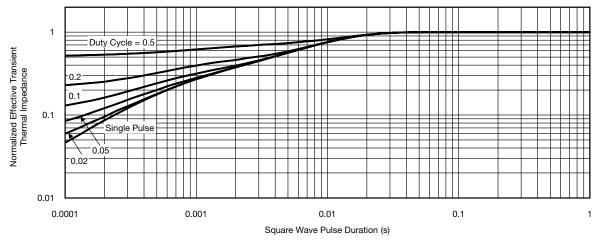
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

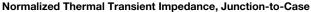


Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)





Note

The characteristics shown in the two graphs

Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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